

Vishay General Semiconductor

Glass Passivated Junction Rectifier



| PRIMARY CHARACTERISTICS | | | | | | |
|-------------------------|-----------------|--|--|--|--|--|
| I _{F(AV)} | 1.0 A | | | | | |
| V _{RRM} | 200 V to 1000 V | | | | | |
| I _{FSM} | 50 A | | | | | |
| I _R | 0.5 μΑ | | | | | |
| V _F | 1.2 V | | | | | |
| T _J max. | 175 °C | | | | | |

FEATURES





· Low forward voltage drop

Low leakage current, I_R less than 0.1 μA

· High forward surge capability

• Meets environmental standard MIL-S-19500

Solder dip 275 °C max. 10 s, per JESD 22-B106

AEC-Q101 qualified

• Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in general purpose rectification of power supplies, inverters, converters and freewheeling diodes application.

MECHANICAL DATA

Case: DO-204AC, molded epoxy over glass body Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant, commercial grade Base P/NHE3 - RoHS compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|--|--|---------------|----------|----------|----------|----------|------|
| PARAMETER | SYMBOL | 1N5614GP | 1N5616GP | 1N5618GP | 1N5620GP | 1N5622GP | UNIT |
| Maximum repetitive peak reverse voltage | V _{RRM} ⁽¹⁾ | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum RMS voltage | V _{RMS} | 140 | 280 | 420 | 560 | 700 | V |
| Maximum DC blocking voltage | V _{DC} (1) | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum average forward rectified current 0.375" (9.5 mm) lead length at $T_A = 55$ °C | I _{F(AV)} | 1.0 | | | | | Α |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | I _{FSM} ⁽¹⁾ | 50 | | | | Α | |
| Operating junction and storage temperature range | T _J , T _{STG} ⁽¹⁾ | - 65 to + 175 | | | | °C | |

Note

(1) JEDEC registered values

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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | | | |
|---|---|-------------------------|--------------------------------|-----------|----------|----------|----------|----------|------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | 1N5614GP | 1N5616GP | 1N5618GP | 1N5620GP | 1N5622GP | UNIT |
| Minimum reverse breakdown voltage | 50 μA | | V _{BR} ⁽¹⁾ | 220 | 440 | 660 | 880 | 1100 | ٧ |
| Maximum instantaneous forward voltage | 1.0 A | | V _F ⁽¹⁾ | 1.2 | | | | | ٧ |
| Maximum DC reverse current | | T _A = 25 °C | I _R ⁽¹⁾ | 0.5 25 | | | | | μА |
| at rated DC blocking voltage | | T _A = 100 °C | IR (*) | | | | | | |
| Maximum reverse recovery time | $I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$ | | t _{rr} ⁽¹⁾ | 2.0 | | | μs | | |
| Maximum junction capacitance | 12 V, 1 MHz | | CJ | 45 | 35 | 25 | 20 | 15 | pF |

Note

⁽¹⁾ JEDEC registered values

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|---|----------------------|----------|------|--|--|------|--|
| PARAMETER SYMBOL 1N5614GP 1N5616GP 1N5618GP 1N5620GP 1N562 | | 1N5622GP | UNIT | | | | |
| Typical thermal resistance | R _{0JA} (1) | 45 | | | | °C/W | |

Note

⁽¹⁾ Thermal resistance from junction to ambient at 0.375" (9.5 mm) lead length, P.C.B. mounted

| ORDERING INFORMATION (Example) | | | | | | | | |
|--------------------------------|-----------------|------------------------|---------------|----------------------------------|--|--|--|--|
| PREFERRED P/N | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | | | |
| 1N5618GP-E3/54 | 0.425 | 54 | 4000 | 13" diameter paper tape and reel | | | | |
| 1N5618GP-E3/73 | 0.425 | 73 | 2000 | Ammo pack packaging | | | | |
| 1N5618GPHE3/54 ⁽¹⁾ | 0.425 | 54 | 4000 | 13" diameter paper tape and reel | | | | |
| 1N5618GPHE3/73 ⁽¹⁾ | 0.425 | 73 | 2000 | Ammo pack packaging | | | | |

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

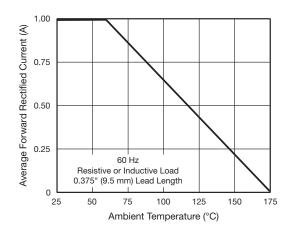


Fig. 1 - Forward Current Derating Curve

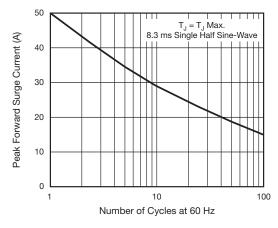


Fig. 2 - Maximum Non-repetitive Peak Forward Surge Current

⁽¹⁾ AEC-Q101 qualified



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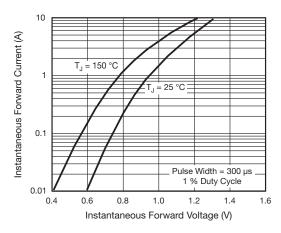


Fig. 3 - Typical Instantaneous Forward Characteristics

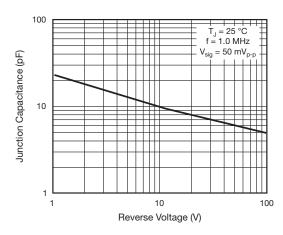


Fig. 5 - Typical Junction Capacitance

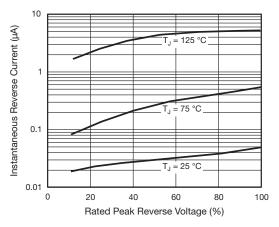
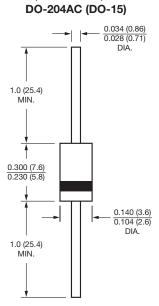


Fig. 4 - Typical Reverse Characteristics

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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